NSN 5961-01-625-5212

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-625-5212 **Inclosure Material:** Plastic **Overall Length:** Between 0.091 inches and 0.106 inches **Overall Height:** 0.043 inches **Overall Width:** Between 0.045 inches and 0.057 inches **Function For Which Designed:** Switching **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 75.0 reverse voltage, average **Current Rating Per Characteristic:** 150.0 milliamperes forward current, dc **Capacitance Rating In Picofarads:** 1.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** -65 to 150 c operating temp **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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